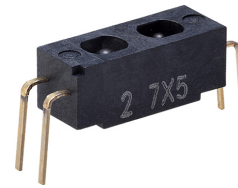


# Photomicrosensor (Reflective)

# EE-SY110

## Compact Reflective Type (Standard Sensing Distance = 5 mm)



Be sure to read *Safety Precautions* on Page 3.

## Ordering Information

### Photomicrosensor

Appearance	Sensing method	Connecting method	Standard sensing distance	Output type	Model	Minimum packing unit (Unit: pcs)
	Reflective	Terminal for PCB mounting	5 mm	Phototransistor	EE-SY110	1

Note: Order in multiples of minimum packing unit.

## Ratings, Characteristics and Exterior Specifications

### Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Rated value	Unit
<b>Emitter</b>			
Forward current	$I_F$	50*1	mA
Pulse forward current	$I_{FP}$	1*2	A
Reverse voltage	$V_R$	4	V
<b>Detector</b>			
Collector-Emitter voltage	$V_{CEO}$	30	V
Emitter-Collector voltage	$V_{ECO}$	—	V
Collector current	$I_C$	20	mA
Collector dissipation	$P_C$	100*1	mW
Operating temperature	$T_{opr}$	-40 to 85	°C
Storage temperature	$T_{stg}$	-40 to 85	°C
Soldering temperature	$T_{sol}$	260*3	°C

\*1. Refer to the temperature rating chart if the ambient temperature exceeds 25°C.

\*2. Pulse width  $\leq 10 \mu s$ , Repeated 100 Hz

\*3. Complete soldering within 10 seconds.

### Exterior Specifications

Connecting method	Weight (g)	Material
		Case
Terminal for PCB mounting	0.4	LCP

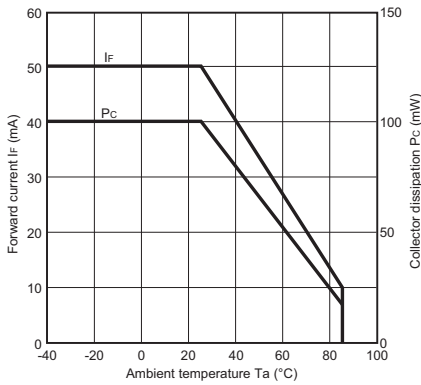
### Electrical and Optical Characteristics (Ta = 25°C)

Item	Symbol	Value			Unit	Condition
		MIN.	TYP.	MAX.		
<b>Emitter</b>						
Forward voltage	$V_F$	—	1.2	1.5	V	$I_F = 30 \text{ mA}$
Reverse current	$I_R$	—	0.01	10	$\mu A$	$V_R = 4 \text{ V}$
Peak emission wavelength	$\lambda_P$	—	940	—	nm	$I_F = 20 \text{ mA}$
<b>Detector</b>						
Light current	$I_L$	200	—	2000	$\mu A$	$I_F = 20 \text{ mA}$ , $V_{CE} = 10 \text{ V}$ Reflectance 90% white paper $d = 5 \text{ mm}^*$
Dark current	$I_D$	—	2	200	nA	$V_{CE} = 10 \text{ V}$ , 0 lx
Leakage current	$I_{LEAK}$	—	—	2	$\mu A$	$I_F = 20 \text{ mA}$ , $V_{CE} = 10 \text{ V}$ Non-reflective state
Collector-Emitter saturated voltage	$V_{CE(sat)}$	—	—	—	V	—
Peak spectral sensitivity wavelength	$\lambda_P$	—	850	—	nm	$V_{CE} = 10 \text{ V}$
Rising time	$t_r$	—	30	—	$\mu s$	$V_{CC} = 5 \text{ V}$ , $R_L = 1 \text{ k}\Omega$ $I_L = 1 \text{ mA}$
Falling time	$t_f$	—	30	—	$\mu s$	$V_{CC} = 5 \text{ V}$ , $R_L = 1 \text{ k}\Omega$ $I_L = 1 \text{ mA}$

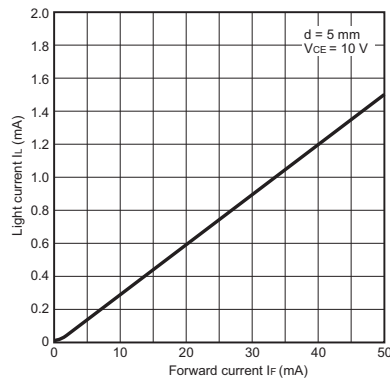
\* "d" is the distance from the top of the sensor to the reflective surface

# Engineering Data (Reference Value)

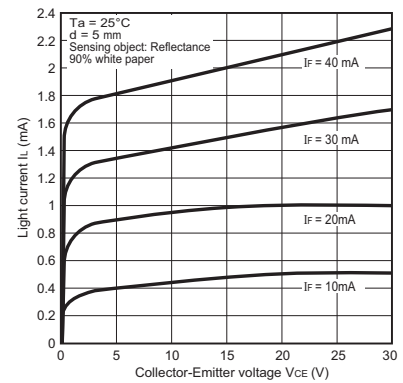
**Fig 1. Forward Current vs. Collector Dissipation Temperature Rating**



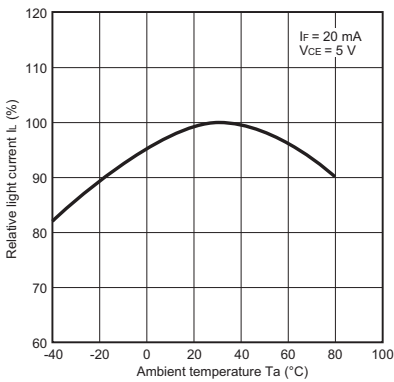
**Fig 2. Light Current vs. Forward Current Characteristics (Typical)**



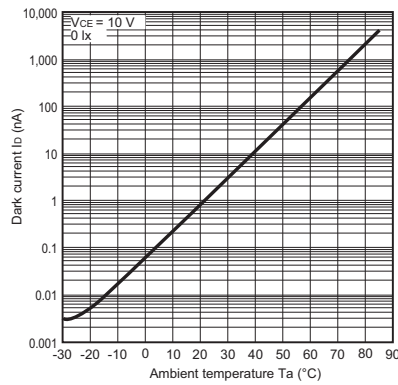
**Fig 3. Light Current vs. Collector-Emitter Voltage Characteristics (Typical)**



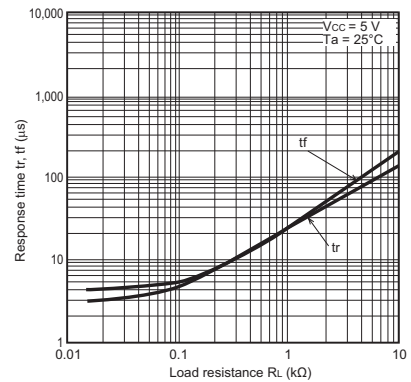
**Fig 4. Relative Light Current vs. Ambient Temperature Characteristics (Typical)**



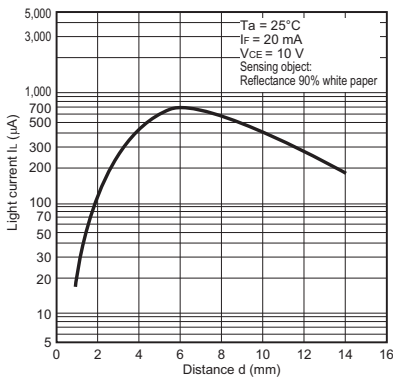
**Fig 5. Dark Current vs. Ambient Temperature Characteristics (Typical)**



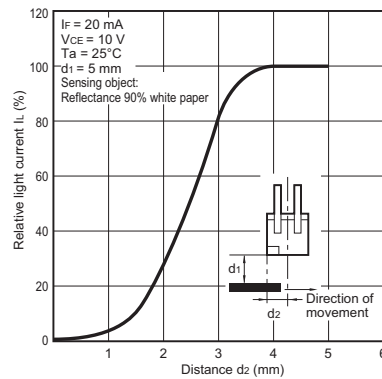
**Fig 6. Response Time vs. Load Resistance Characteristics (Typical)**



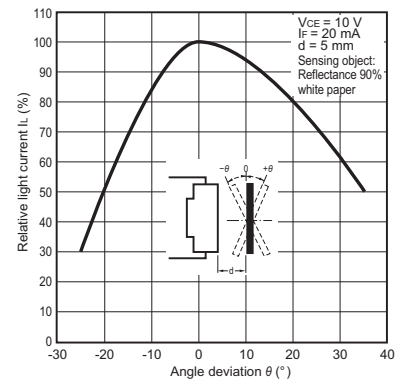
**Fig 7. Sensing Distance Characteristics (Typical)**



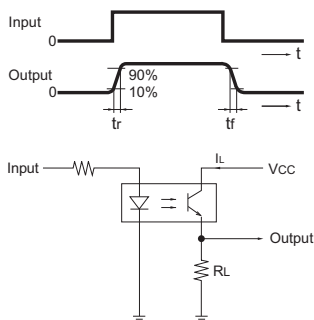
**Fig 8. Sensing Position Characteristics (Typical)**



**Fig 9. Sensing Angle Characteristics (Typical)**



**Fig 10. Response Time Measurement Circuit**



## Safety Precautions

To ensure safe operation, be sure to read and follow the Instruction Manual provided with the Sensor.

### CAUTION

This product is not designed or rated for ensuring safety of persons either directly or indirectly. Do not use it for such purposes.



### Precautions for Correct Use

Do not use the product in atmospheres or environments that exceed product ratings.

### Precautions for Safe Use

Do not use the product with a voltage or current that exceeds the rated range.

Applying a voltage or current that is higher than the rated range may result in explosion or fire.

Do not miswire such as the polarity of the power supply voltage.

Otherwise the product may be damaged or it may burn.

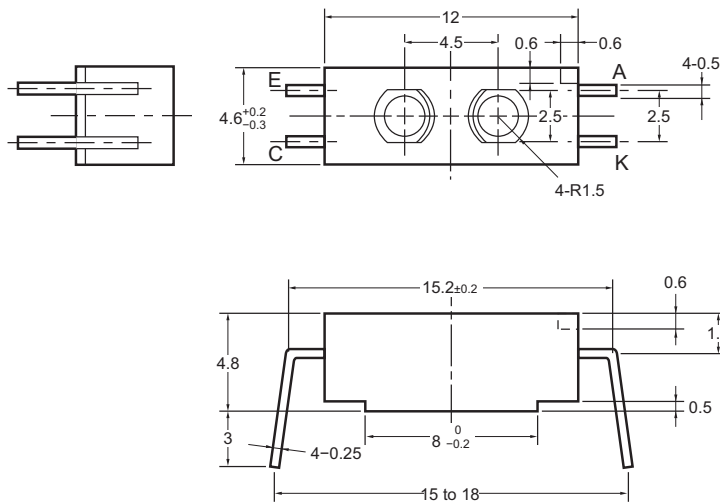
This product does not resist water. Do not use the product in places where water or oil may be sprayed onto the product.

## Dimensions and Internal Circuit

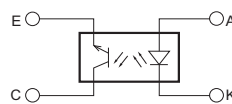
(Unit: mm)

### Photomicrosensor

EE-SY110



Internal circuit



Terminal No.	Name
A	Anode
K	Cathode
C	Collector
E	Emitter

Unless otherwise specified, the tolerances are as shown below.

Dimensions	Tolerance
3 mm max.	±0.2
3 < mm ≤ 6	±0.24
6 < mm ≤ 10	±0.29
10 < mm ≤ 18	±0.35
18 < mm ≤ 30	±0.42

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